

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China

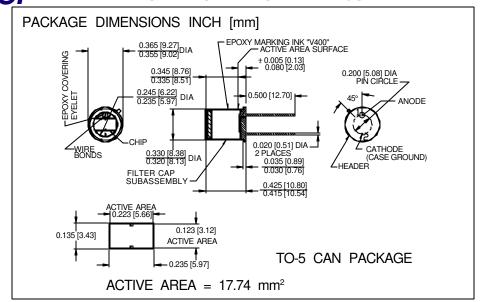






PHOTONIC Silicon Photodiode, Filter Combination Photovoltaic (photopic response) Type PDV-V400 DETECTORS INC.





RESPONSIVITY (A/W)

FEATURES

- Large active area
- High transmission
- Low noise

DESCRIPTION

The PDV-V400 is a silicon, PIN planar diffused, photodiode with a photopic response filter. The detector filter combination has a wide bandwidth designed to simulate the spectral response of the human eye.

Packaged in a TO-5 metal can. **ABSOLUTE MAXIMUM RATING** (TA=25°C unless otherwise noted)

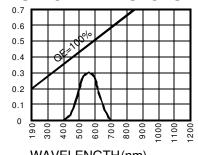
SYMBOL	PARAMETER	MIN	MAX UNITS	
V _{BR}	Reverse Voltage		100	V
T_{STG}	Storage Temperature	-20	+85	⊙C
То	Operating Temperature Range	-15	+70	⊙C
Ts	Soldering Temperature*		+240	∘C
IL	Light Current		0.5	mA

^{*1/16} inch from case for 3 secs max

APPLICATIONS

- Photometry
- Radiometry
- Film color processing

SPECTRAL RESPONSE



WAVELENGTH(nm)

ELECTRO-OPTICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Isc	Short Circuit Current***	H = 100 fc, 2850 K	150	200		μΑ
ΙD	Dark Current	H = 0, V _R = 10 mV		10	50	pА
RsH	Shunt Resistance	H = 0, V _R = 10 mV	.20	2		GΩ
TC Rsh	Rsh Temp. Coefficient	H = 0, V _R = 10 mV		-8		%/°C
CJ	Junction Capacitance	H = 0, V _R = 10 V**		1700		рЕ
CWL	Center Wavelength	(CWL, λ o) +/- 2 nm		525		nm
HBW	Half Bandwidth	(FWHM)		150		nm
VBR	Breakdown Voltage	I = 10 µuA	50	75		V
NEP	Noise Equivalent Power	V _R = 10 mV @ Peak		9x10 ⁻¹⁵		W/ √ Hz
tr	Response Time	RL = 1 KΩ V _R = 10 V		1.0		μ S

Information in this technical data sheet is believed to be correct and reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice.**f = 1 MHz, *** without filter [FORMNO.100-PDV-V400 REV C]